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August 2013

FFB3946 / FMB3946 NPN & PNP General-Purpose Amplifier

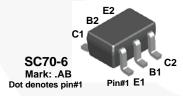
Description

This complementary device is designed for use as a general-purpose amplifier and switch, The useful dynamic range extends to 100 mA as a switch and 100 MHz as an amplifier. Sourced from Process 23 and 66. See FFB3904 (NPN) and FFB3906 (PNP) for characteristics.

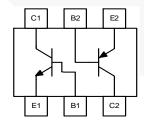
Ordering Information

| Part Number | Top Mark | Package | Packing Method |
|-------------|----------|---------|----------------|
| FFB3946 | AB | SC70 6L | Tape and Reel |
| FMB3946 | 002 | SSOT 6L | Tape and Reel |

Block Diagram

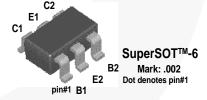


FFB3946 Device Package

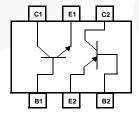


FFB3946 Internal Connection

TRANSISTOR TYPE
C1 B1 E1 NPN
C2 B2 E2 PNP



FMB3946 Device Package



FMB3946 Internal Connection

Figure 1. Block Diagram

Absolute Maximum Ratings(1)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Value | Units |
|-----------------------------------|----------------------------------|-------------|-------|
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{CBO} | Collector-Base Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 5.0 | V |
| I _C | Collector Current - Continuous | 200 | mA |
| T _J , T _{stg} | Junction and Storage Temperature | -55 to +150 | °C |

Notes:

- 1. These ratings are based on a maximum junction temperature of 150 $^{\circ}\text{C}.$
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.
- 3. All voltages (V) and currents (A) are negative polarity for PNP transistors.
- 4. These ratings are limiting values above which serviceability of any semiconductor advice may be impaired.

Thermal Characteristics(2)

Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Maxi | Units | |
|-----------------|---|---------|---------|--------|
| | | FFB3946 | FMB3946 | Ullits |
| P _D | Total Device Dissipation | 300 | 700 | mW |
| | Derate Above 25°C | 2.4 | 5.6 | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 415 | 180 | °C/W |

Note:

2. PCB board size: FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics(3)

Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|----------------------|--------------------------------------|--|------|------|------|-------|
| Off Charac | cteristics | | 1 | l. | I. | |
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{ mA}, I_B = 0$ | 40 | | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 40 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 5.0 | | | V |
| I _{CBO} | Collector Cut-Off Current | $V_{CB} = 30 \text{ V}, I_{E} = 0$ | | | 50 | nA |
| I _{EBO} | Emitter Cut-Off Current | $V_{EB} = 4.0 \text{ V}, I_{C} = 0$ | | | 50 | nA |
| On Charac | cteristics | | | • | | |
| h _{FE} | | $I_C = 100 \mu\text{A}, V_{CE} = 1.0 \text{V}$ | 40 | | | |
| | | $I_C = 1.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 70 | | | |
| | DC Current Gain | $I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 100 | | 300 | |
| | | $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 60 | | | |
| | | I _C = 100 mA, V _{CE} = 1.0 V | 30 | | | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 10 mA, I _B = 1.0 mA | | | 0.25 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 10 mA, I _B = 1.0 mA | | | 0.9 | V |
| | nal Characteristics | | | | | |
| f _T | Current Gain-Bandwidth Product | $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz | | 200 | | MHz |
| C _{obo} | Output Capacitance | V _{CB} = 5.0 V, f = 100 kHz | | 4.5 | | pF |
| C _{ibo} | Input Capacitance | $V_{CB} = 0.5 \text{ V, f} = 100 \text{ kHz}$ | | 10 | | pF |

Note:

3. All voltages (V) and currents (A) are negative polarity for PNP transistors.

Physical Dimensions

SC70 6L

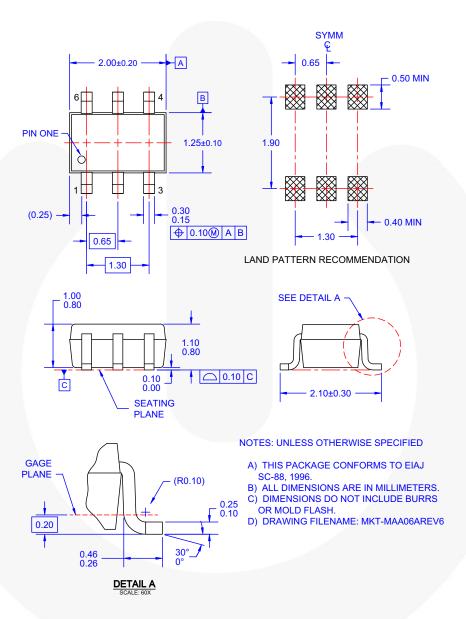


Figure 2. 6-LEAD, SC70, EIAJ SC-88, 1.25 MM WIDE (ACTIVE)

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Physical Dimensions (Continued)

SSOT 6L

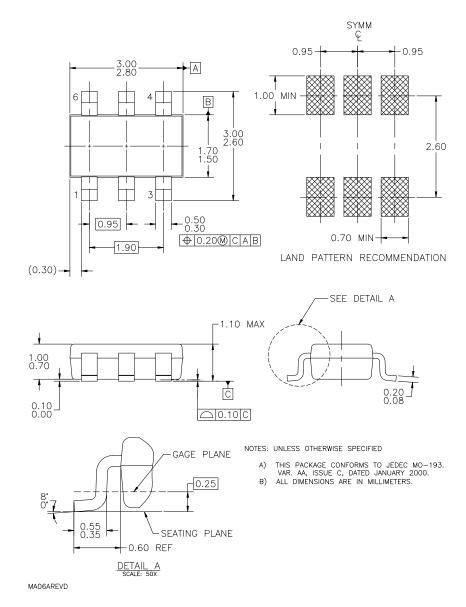


Figure 3. 6-LEAD, SUPERSOT6, JDEC MO-193, 1.6 MM WIDE (ACTIVE)

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| Definition of Terms | | | | |
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